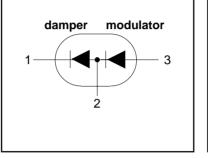
BYM357X

FEATURES

- Low forward volt drop
- · Fast switching
- Soft recovery characteristicHigh thermal cycling

- Isolated mounting tab

SYMBOL



QUICK REFERENCE DATA

	MODULATOR
V _R =1500 V	V _R =600 V
$V_F \leq 1.3 \text{ V}$	$V_F \le 1.03 \text{ V}$
I _{F(RMS)} =15.7 A	V_{R} =600 V V_{F} ≤ 1.03 V I _{F(RMS)} = 13 A I _{FSM} ≤ 100 A
$I_{FSM} \le 60 \text{ A}$	$I_{FSM} \le 100 \text{ A}$
t _{rr} ≤ 300 ns	t _{rr} ≤ 60 ns

GENERAL DESCRIPTION

Combined damper and modulator diodes in an isolated plastic envelope for horizontal deflection in colour TV and PC monitors. The BYM357X contains diodes with performance characteristics designed specifically for applications from 16kHz to 70kHz

The BYM357X series is supplied in the conventional leaded SOT186A package.

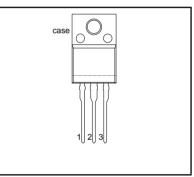
LIMITING VALUES

 $T_i = 25$ °C unless otherwise stated

PINNING

- PIN DESCRIPTION 1 damper cathode
- 2 common anode/cathode
- 3 modulator anode.

SOT186A



-			DAN	IPER	MODU	LATOR	
SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	MIN	MAX	UNIT
V _{RSM}	Peak non-repetitive reverse voltage.		-	1500	-	600	V
V_{RRM}	Peak repetitive reverse voltage		-	1500	-	600	V
V_{RWM}	Crest working reverse voltage		-	1300	-	600	V
I _{F(AV)} I _{F(RMS)} I _{FRM}	Average forward current RMS forward current Peak repetitive forward current	sinusoidal;a=1.57 t=25 μs δ= 0.5 T _{hs} ≤ 83 °C	- - -	10 15.7 20	- - -	9 13 18.0	A A A
I _{FSM}	Peak non-repetitive forward current	$ t = 10 \text{ms} t = 8.3 \text{ ms} sinusoidal; with reapplied V_{RWM(MAX)} $	-	60 66	-	100 110	A A
T _{stg} T _J	Storage temperature Operating junction temperature		-40 -	150 150	-40 -	150 150	Ĵ Ĵ

BYM357X

ISOLATION LIMITING VALUE & CHARACTERISTIC

 $T_{hs} = 25$ °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _{isol}	R.M.S. isolation voltage from all three terminals to external heatsink	f = 50-60 Hz; sinusoidal waveform; R.H. \leq 65% ; clean and dustfree	-		2500	V
C _{isol}	Capacitance from T2 to external heatsink	f = 1 MHz	-	10	-	pF

THERMAL RESISTANCES

	DAMPER MODULATOR						
SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	TYP.	MAX.	UNIT
R _{th j-hs}	Thermal resistance junction to heatsink	with heatsink compound	-	4.8	-	5.5	K/W
R _{th j-a}	Thermal resistance junction to ambient	in free air.	55	-	55	-	K/W

STATIC CHARACTERISTICS OF DAMPER

 $T_j = 25$ °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	TYP	MAX.	UNIT
V _F I _R	Forward voltage Reverse current		1.1 1.05 10 50	1.45 1.3 250 500	ν ν μΑ μΑ

STATIC CHARACTERISTICS OF MODULATOR

 $T_i = 25$ °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	TYP	MAX.	UNIT
V _F	Forward voltage	I _F = 8 A I _F = 8 A; T _i = 125°C	1.2 0.9	1.3 1.03	V V
I _R	Reverse current.	$\dot{V}_{R} = V_{RWM}$ $V_{R} = V_{RWM}$ $T_{j} = 100 \degree C$	10 100	50 350	μΑ μΑ

BYM357X

ELECTRICAL CHARACTERISTICS OF DAMPER

 $T_i = 25$ °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
t _{rr}	Reverse recovery time	$I_F = 1 \text{ A}; V_R \ge 30 \text{ V};$ - $dI_F/dt = 50 \text{ A/}\mu\text{s}$	200	300	ns
Q _s V _{fr}	Reverse recovery charge Peak forward recovery voltage	2 Å,30 V,20 Å/ μ s I _F = 6.5 Å; dI _F /dt = 50 Å/ μ s	1.2 27	2.0 -	μC V

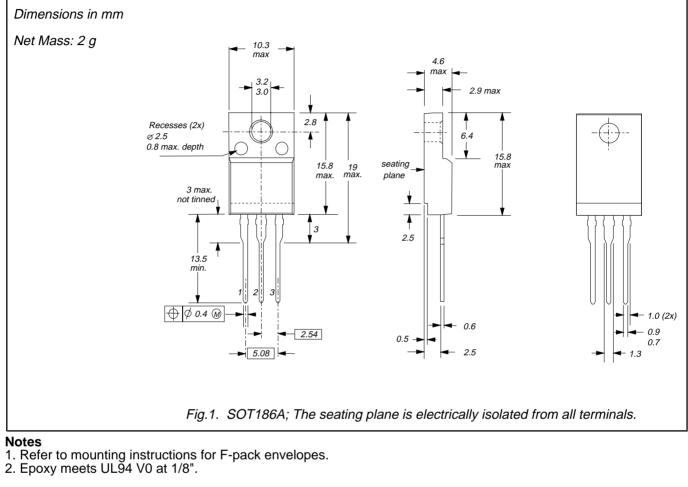
ELECTRICAL CHARACTERISTICS OF MODULATOR

 $T_i = 25$ °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
t _{rr}	Reverse recovery time	I _F = 1 A; V _R ≥ 30 V; -dI _F /dt = 100 A/μs	45	60	ns
Q _s V _{fr}	Reverse recovery charge Peak forward recovery voltage	$I_{\rm F} = 100 \text{A/}\mu\text{s}$ 2 A,30 V,20 A/ μs $I_{\rm F} = 10 \text{A};$ $dI_{\rm F}/dt = 10 \text{A/}\mu\text{s}$	40 2.5	60 -	nC V

BYM357X

MECHANICAL DATA



BYM357X

DEFINITIONS

Data sheet status					
Objective specification This data sheet contains target or goal specifications for product development.					
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.				
Product specification	This data sheet contains final product specifications.				
Limiting values					
Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.					
Application information					
Where application information is given, it is advisory and does not form part of the specification.					
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